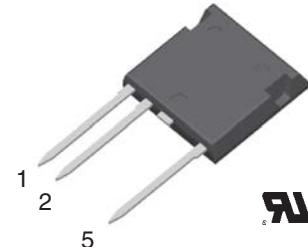
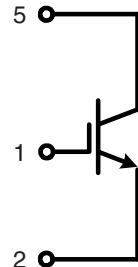


High Voltage IGBT

in High Voltage
ISOPLUS i4-PAC™

I_{C25} = 32 A
 V_{CES} = 2500 V
 $V_{CE(sat)}$ = 3.2 V
 t_f = 250 ns



IGBT

Symbol	Conditions	Maximum Ratings		
V_{CES}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	2500		V
V_{GES}		± 20		V
I_{C25}	$T_C = 25^\circ\text{C}$	32		A
I_{C90}	$T_C = 90^\circ\text{C}$	19		A
I_{CM}	$V_{GE} = \pm 15 \text{ V}$; $R_G = 47 \Omega$; $T_{VJ} = 125^\circ\text{C}$	70		A
V_{CEK}	RBSOA, Clamped inductive load; $L = 100 \mu\text{H}$	1200		V
P_{tot}	$T_C = 25^\circ\text{C}$	250		W

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
$V_{CE(sat)}$	$I_C = 19 \text{ A}$; $V_{GE} = 15 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	3.2 4.7	3.9	V V
$V_{GE(th)}$	$I_C = 1 \text{ mA}$; $V_{GE} = V_{CE}$	5	8	V
I_{CES}	$V_{CE} = V_{CES}$; $V_{GE} = 0 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	0.2	0.15	mA mA
I_{GES}	$V_{CE} = 0 \text{ V}$; $V_{GE} = \pm 20 \text{ V}$		500	nA
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	Inductive load, $T_{VJ} = 125^\circ\text{C}$ $V_{CE} = 1500 \text{ V}$; $I_C = 19 \text{ A}$ $V_{GE} = \pm 15 \text{ V}$; $R_G = 47 \Omega$	100 50 600 250 15 30		ns ns ns ns mJ mJ
C_{ies} C_{oes} C_{res}		2.28 103 43		nF pF pF
Q_{Gon}		142		nC
R_{thJC}			0.5	K/W

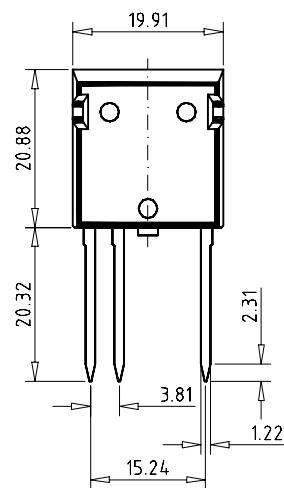
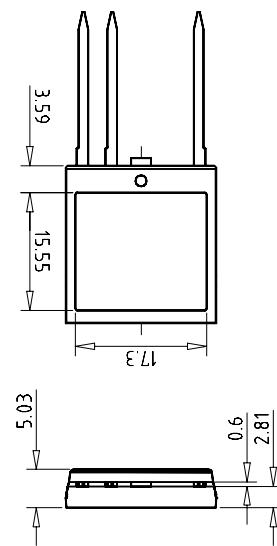
IXYS reserves the right to change limits, test conditions and dimensions.

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Component

Symbol	Conditions	Maximum Ratings	
T_{VJ}		-55...+150	°C
T_{stg}		-55...+125	°C
V_{ISOL}	$I_{ISOL} \leq 1$ mA; 50/60 Hz	2500	V~
F_c	mounting force with clip	20...120	N

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
d_s, d_A	C pin - E pin	7.0		mm
d_s, d_A	pin - backside metal	5.5		mm
R_{thCH}	with heatsink compound	0.15		K/W
Weight		9		g

Dimensions in mm (1 mm = 0.0394")

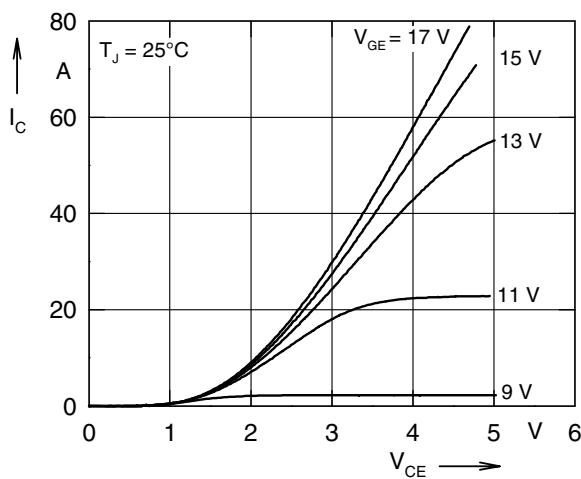


Fig. 1 Typ. Output Characteristics

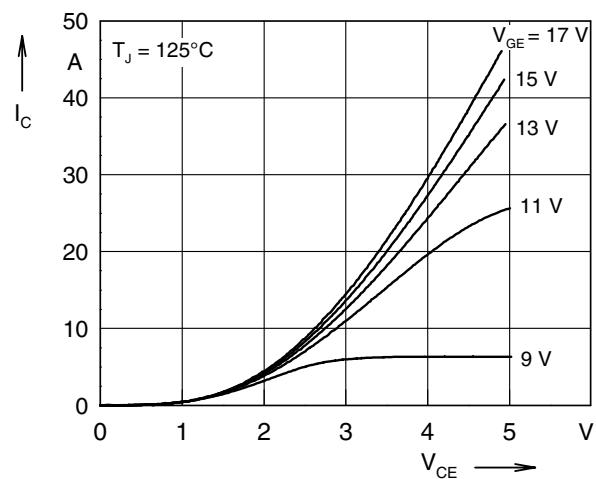


Fig. 2 Typ. Output Characteristics

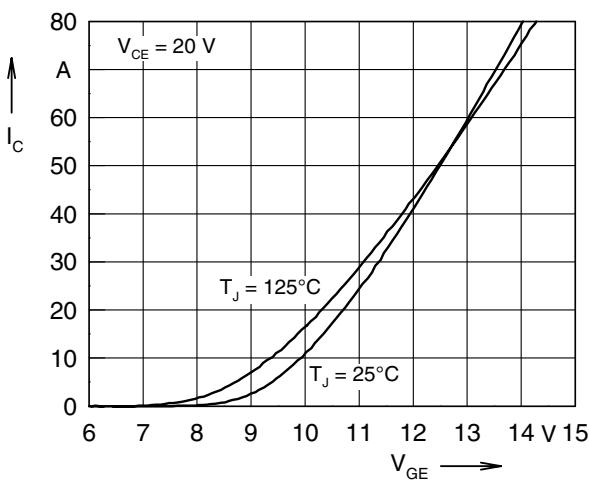


Fig. 3 Typ. Transfer Characteristics

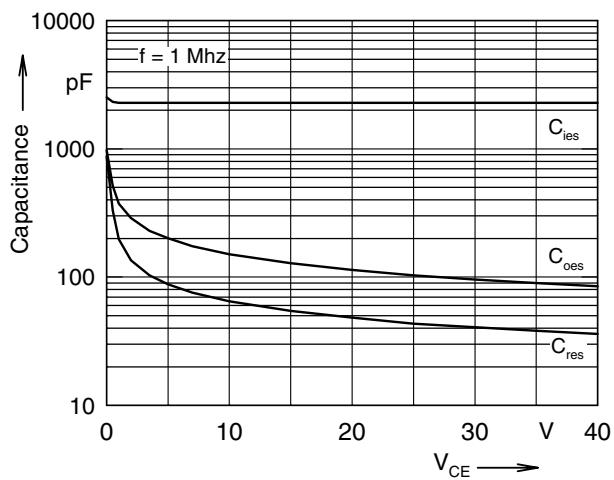


Fig. 4 Capacitance curves

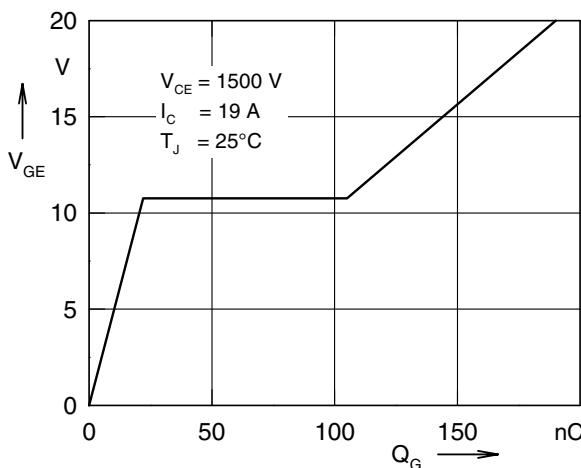


Fig. 5 Typ. Gate Charge characteristics

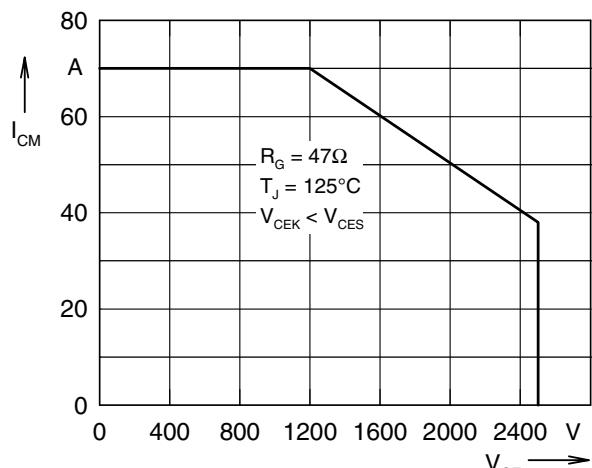


Fig. 6 Reverse Biased Safe Operating Area RBSOA

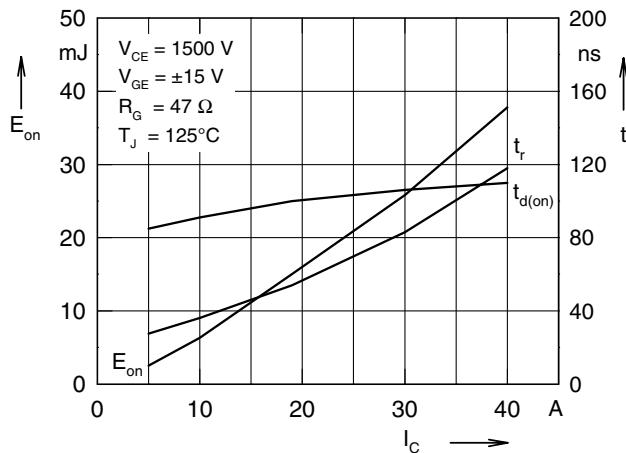


Fig. 7 Typ. turn on energy and switching times versus collector current

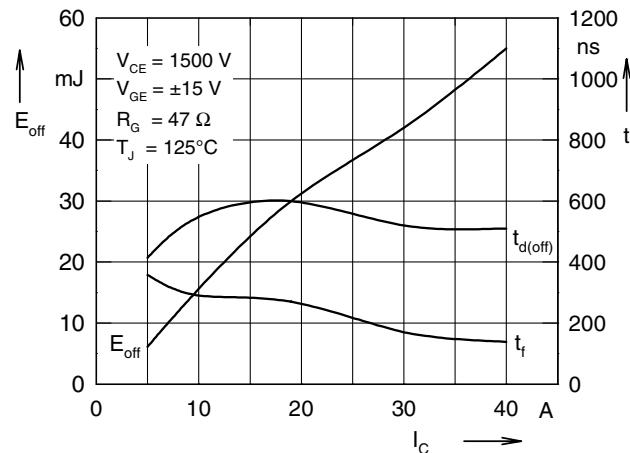


Fig. 8 Typ. turn off energy and switching times versus collector current

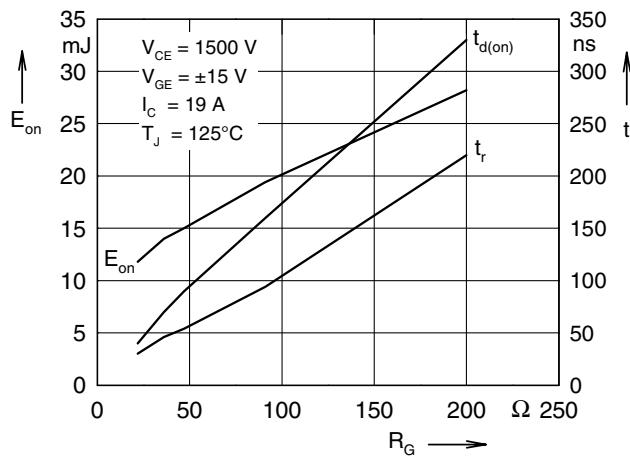


Fig. 9 Typ. turn on energy and switching times versus gate resistor

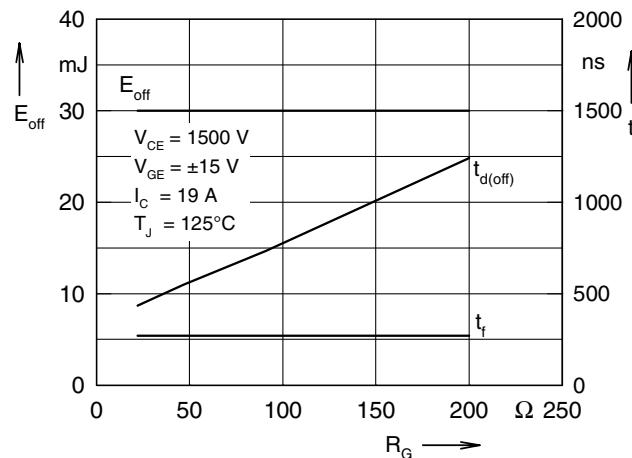


Fig. 10 Typ. turn off energy and switching times versus gate resistor

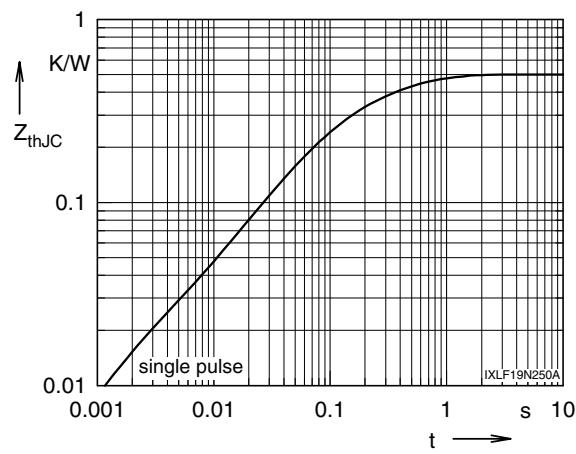


Fig. 11 Typ. transient thermal impedance